

MCP87050

High-Speed N-Channel Power MOSFET

Features:

- Low Drain-to-Source On Resistance (R_{DS(ON)})
- Low Total Gate Charge (Q_G) and Gate-to-Drain Charge (Q_{GD})
- · Low Series Gate Resistance (RG)
- · Fast Switching
- · Capable of Short Dead-Time Operation
- · RoHS Compliant

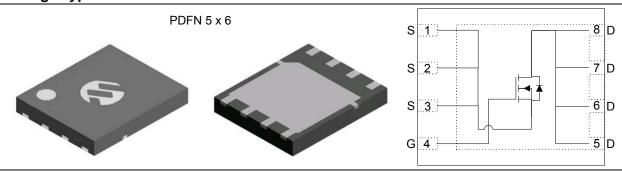
Applications

- · Point-of-Load DC-DC Converters
- High Efficiency Power Management in Servers, Networking, and Automotive Applications

Description

The MCP87050 is an N-Channel power MOSFET in a popular PDFN 5 mm x 6 mm package. Advanced packaging and silicon processing technologies allow the MCP87050 to achieve a low Q_{G} for a given $R_{DS(ON)}$ value, resulting in a low Figure of Merit (FOM). Combined with low R_{G} the low Figure of Merit of the MCP87050 allows high efficiency power conversion with reduced switching and conduction losses.

Package Type



Product Summary Table: Unless otherwise indicated, T _A = +25°C									
Parameters Sym Min Typ Max Units C						Conditions			
Operating Characteristics									
Drain-to-Source Breakdown Voltage	BV _{DSS}	25	_	_	V	$V_{GS} = 0V, I_D = 250 \mu A$			
Gate-to-Source Threshold Voltage	V _{GS(TH)}	1	1.3	1.6	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$			
Drain-to-Source On Resistance	R _{DS(ON)}	_	5.0	6.0	mΩ	V _{GS} = 4.5V, I _D = 20A			
		_	4.2	5.0	mΩ	V _{GS} = 10V, I _D = 20A			
Total Gate Charge	Q_G	_	12.5	15	nC	V_{DS} = 12.5V, I_{D} = 20A, V_{GS} = 4.5V			
Gate-to-Drain Charge	Q_{GD}	_	4.7	_	nC	V _{DS} = 12.5V, I _D = 20A			
Series Gate Resistance	R_{G}	_	1.1	_	Ω				
Thermal Characteristics									
Thermal Resistance Junction-to-X	$R_{\theta JX}$	_	_	56	°C/W	Note 1			
Thermal Resistance Junction-to-Case	$R_{\theta JC}$	_	_	1.9	°C/W	Note 2			

- **Note 1:** R_{0JX} is determined with the device surface mounted on a 4-Layer FR4 PCB, with a 1" x 1" mounting pad of 2 oz. copper. This characteristic is dependent on user's board design.
 - 2: R_{B,IC} is determined using JEDEC 51-14 Method. This characteristic is determined by design.

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

V _{DS}	+25V
V _{GS}	+10.0V / -8V
I _{D,} Continuous	100A, $T_C = +25^{\circ}C$
P _D	2.2W, T _A = +25°C
T _J , T _{STG}	55°C to +150°C
E _{AS} Avalanche Energy	162 mJ
$I_D = 18A, L = 1 \text{ mH}, R_G = 2$	25Ω

† Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

Electrical Characteristics: Unless otherwise indicated, T _A = +25°C									
Parameters	Sym	Min	Тур	Max	Units	Conditions			
Static Characteristics									
Drain-to-Source Breakdown Voltage	B _{VDSS}	25	_	_	V	V _{GS} = 0V, I _D = 250 μA			
Drain-to-Source Leakage Current	I _{DSS}	_		1	μΑ	V _{GS} = 0V, V _{DS} = 20V			
Gate-to-Source Leakage Current	I _{GSS}		_	100	nA	V _{DS} = 0V, V _{GS} = 10V/-8V			
Gate-to-Source Threshold Voltage	V _{GS(TH)}	1	1.3	1.6	V	V _{DS} = V _{GS} , I _D = 250 μA			
Drain-to-Source On Resistance	R _{DS(ON)}	_	5	6.0	mΩ	V _{GS} = 4.5V, I _D = 20A			
	, ,		4.2	5	mΩ	V _{GS} = 10V, I _D = 20A			
Transconductance	9 _{fs}	_	101		S	V _{DS} = 12.5V, I _D = 20A			
Dynamic Characteristics	•			•					
Input Capacitance	C _{ISS}	_	1040	_	pF	$V_{GS} = 0V, V_{DS} = 12.5V, f = 1 MHz$			
Output Capacitance	Coss	_	490		pF	$V_{GS} = 0V, V_{DS} = 12.5V, f = 1 MHz$			
Reverse Transfer Capacitance	C _{RSS}	_	140		pF	$V_{GS} = 0V, V_{DS} = 12.5V, f = 1 MHz$			
Total Gate Charge	Q_{G}		12.5	15	nC	$V_{DS} = 12.5V$, $I_{D} = 20A$, $V_{GS} = 4.5V$			
Gate-to-Drain Charge	Q_{GD}	_	4.7		nC	V _{DS} = 12.5V, I _D = 20A			
Gate-to-Source Charge	Q_{GS}	_	1.9	_	nC	V _{DS} = 12.5V, I _D = 20A			
Gate Charge at V _{GS(TH)}	Q _{G(TH)}		1.4	_	nC	$V_{DS} = 12.5V, I_{D} = 20A$			
Output Charge	Q _{OSS}	_	9.5		nC	V _{DS} = 12.5V, V _{GS} = 0			
Turn-On Delay Time	t _{d(on)}	_	5	_	ns	V_{DS} = 12.5V, V_{GS} = 4.5V, I_{D} = 20A, R_{G} = 2 Ω			
Rise Time	t _r		18	_	ns	V_{DS} = 12.5V, V_{GS} = 4.5V, I_{D} = 20A, R_{G} = 2 Ω			
Turn-Off Delay Time	t _{d(off)}	_	11	_	ns	V_{DS} = 12.5V, V_{GS} = 4.5V, I_{D} = 20A, R_{G} = 2 Ω			
Fall Time	t _f	_	5	_	ns	V_{DS} = 12.5V, V_{GS} = 4.5V, I_{D} = 20A, R_{G} = 2 Ω			
Series Gate Resistance	R_{G}	_	1.1	_	Ω				

DC ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics: Unless otherwise indicated, T _A = +25°C									
Parameters Sym Min Typ Max Units Conditions									
Diode Characteristics									
Diode Forward Voltage	V _{FD}	_	0.8	1	V	I _S = 20A, V _{GS} = 0V			
Reverse Recovery Charge	Q _{RR}	_	20	_	nC	I _S = 20A, di/dt = 300 A/μs			
Reverse Recovery Time	t _{rr}	_	16	_	ns	I _S = 20A, di/dt = 300 A/μs			
Avalanche Characteristics									
Avalanche Energy	E _{AS}	50	_	_	mJ	I_D = 10A, L = 1 mH, R _G = 25 Ω			

TEMPERATURE CHARACTERISTICS

Electrical Characteristics: Unless otherwise indicated, T _A = +25°C							
Parameters	Sym	Min	Тур	Max	Units	Conditions	
Temperature Ranges							
Operating Junction Temperature Range	TJ	-55	_	150	°C		
Storage Temperature Range	T _A	-55	_	150	°C		
Package Thermal Resistances							
Thermal Resistance Junction-to-X, 8L 5x6-PDFN	$R_{\theta JX}$	_	_	56	°C/W	Note 1	
Thermal Resistance Junction-to-Case, 8L 5x6-PDFN	$R_{\theta JC}$	_	_	1.9	°C/W	Note 2	

Note 1: R_{0JX} is determined with the device surface mounted on a 4-Layer FR4 PCB, with a 1" x 1" mounting pad of 2 oz. copper. This characteristic is dependent on user's board design.

^{2:} $R_{\theta JC}$ is determined using JEDEC 51-14 Method. This characteristic is determined by design.

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Note: Unless otherwise indicated, $T_A = +25$ °C.

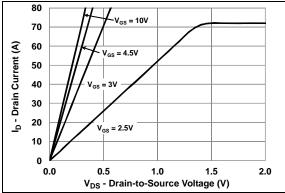


FIGURE 2-1: Typical Output Characteristics.

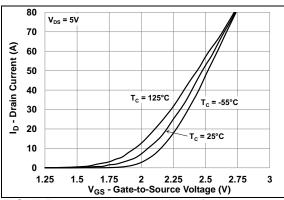


FIGURE 2-2: Typical Transfer Characteristics.

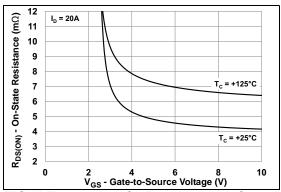


FIGURE 2-3: On Resistance vs. Gate-to-Source Voltage.

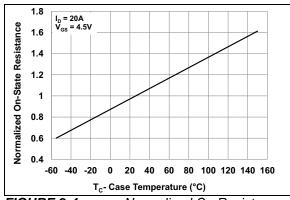


FIGURE 2-4: Normalized On Resistance vs. Temperature.

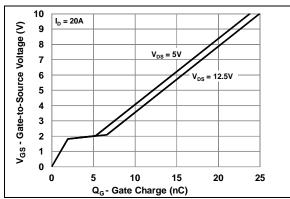


FIGURE 2-5: Gate-to-Source Voltage vs. Gate Charge.

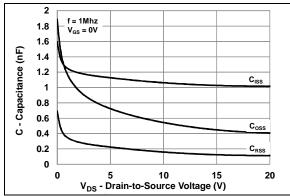


FIGURE 2-6: Capacitance vs. Drain-to-Source Voltage.

Note: Unless otherwise indicated, $T_A = +25$ °C.

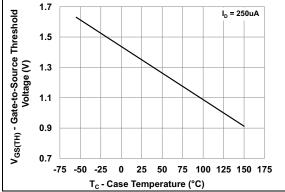


FIGURE 2-7: Gate-to-Source Threshold Voltage vs. Temperature.

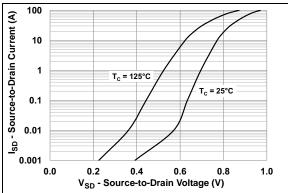


FIGURE 2-8: Source-to-Drain Current vs. Source-to-Drain Voltage.

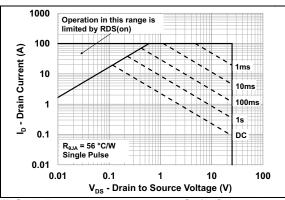


FIGURE 2-9: Maximum Safe Operating Area.

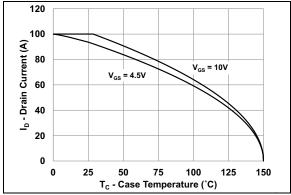


FIGURE 2-10: Maximum Drain Current vs. Temperature.

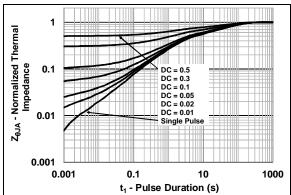


FIGURE 2-11: Transient Thermal Impedance.

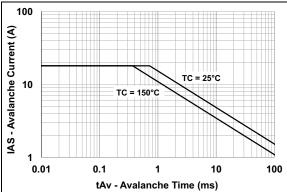


FIGURE 2-12: Single-Pulse Unclamped Inductive Switching.

MCP87050

Note: Unless otherwise indicated, $T_A = +25$ °C.

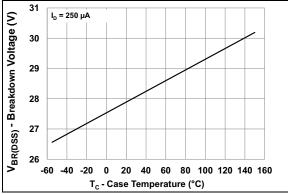


FIGURE 2-13: Drain-to-Source Breakdown Voltage vs. Temperature.

3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

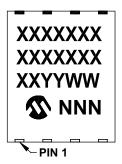
TABLE 3-1: PINOUT DESCRIPTION FOR THE MCP87050

MCP87050	Din Tyno	Function
5x6 PDFN	Pin Type	Function
1, 2, 3	S	Source pin
4	G	Gate pin
5, 6, 7, 8	D	Drain pin, including exposed thermal pad

4.0 PACKAGING INFORMATION

4.1 Package Marking Information*

8-Lead PDFN (5x6x1.0 mm)





*RoHS compliant using EU-RoHS exemption: 7(a) - Lead in high-melting-temperature-type solders (i.e. lead-based alloys containing 85% by weight or more lead) can be found on the outer packaging for this package.

Legend: XX...X Customer-specific information

Y Year code (last digit of calendar year)
YY Year code (last 2 digits of calendar year)
WW Week code (week of January 1 is week '01')

NNN Alphanumeric traceability code

(e3) Pb-free JEDEC designator for Matte Tin (Sn)

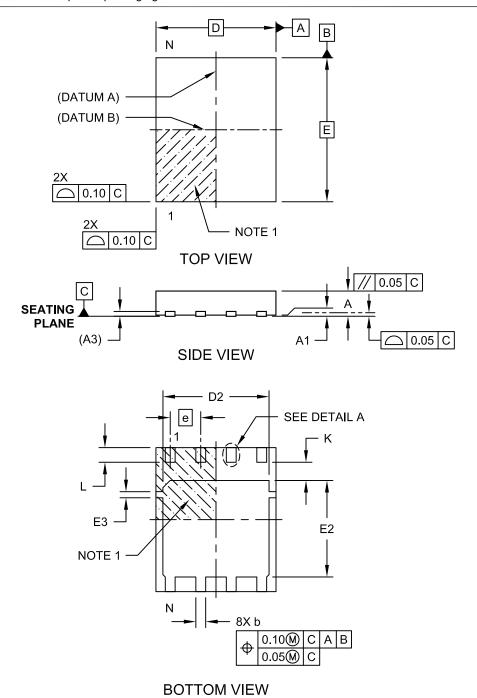
This package is Pb-free. The Pb-free JEDEC designator (@3)

can be found on the outer packaging for this package.

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

8-Lead Power Dual Flatpack No Lead Package (MF) - 5x6x1.0 mm Body [PDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging

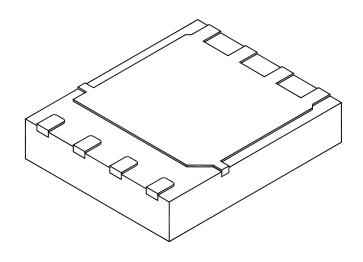


Microchip Technology Drawing C04-188B Sheet 1 of 2

8-Lead Power Dual Flatpack No Lead Package (MF) - 5x6x1.0 mm Body [PDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging





	Units	MILLIMETERS		
Dimension	Limits	MIN	NOM	MAX
Number of Pins	N	8		
Pitch	е		1.27 BSC	
Overall Height	Α	0.80	1.00	1.03
Standoff	A1	0.00	-	0.05
Terminal Thickness	(A3)	0.20 REF		
Overall Length	D	5.00 BSC		
Overall Width	E	6.00 BSC		
Exposed Pad length	D2	4.27	4.42	4.52
Exposed Pad Width	E2	3.87	4.02	4.12
Tab Width	E3	0.20	0.25	0.30
Terminal Width	b	0.36	0.41	0.46
Terminal Length	L	0.51	0.61	0.71
Terminal to Exposed Pad	K	0.71	0.76	0.81

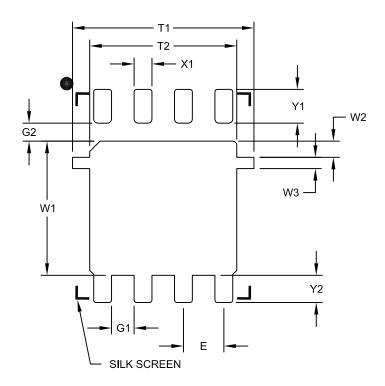
Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated.
- 3. Package dimension does not include mold flash, protrusions, burrs or metal smearing.
- 4. Dimensioning and tolerancing per ASME Y14.5M.
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
 - REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-188B Sheet 2 of 2

8-Lead Power Dual Flatpack No Lead Package (MF) – 5x6x1.0 mm Body [PDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension	MIN	NOM	MAX	
Contact Pitch	Е			
Center Pad Width	W1			4.22
Pad Edge to Tab	W2		0.51	
Tab Width	W3		0.35	
Center Pad Length With Tabs	T1			5.70
Center Pad Length	T2			4.62
Distance Between Terminals	G1	0.71		
Terminal To Center Pad (X4)	G2	0.57		
Terminal Pad Width (X8)	X1			0.56
Terminal Pad Length (X4)	Y1			1.06
Terminal Pad Length (X8)	Y2			0.86

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2188A

MCP87050

NOTES:

APPENDIX A: REVISION HISTORY

Revision B (November 2012)

- Updated the Q_{GD} value in the Product Summary table and the DC Electrical Characteristics table.
- Updated the Thermal Resistance Junction-to-Case value in the Temperature Characteristics table
- Replaced Figure 2-10 and Figure 2-13.

Revision A (September 2012)

· Original Release of this Document.

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO. Example: Device Temperature **Package** MCP87050T-U/MF: Tape and Reel, Extended Temperature, 8LD PDFN package Range Device: MCP87050T: N-Channel power MOSFET (Tape and Reel) (PDFN) Temperature Range: U = -55°C to +150°C (Ultra High) MF = Plastic Dual Flat, No Lead Package Package: (5x6x1.0 mm Body) (PDFN), 8-lead

Note the following details of the code protection feature on Microchip devices:

- · Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our
 knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data
 Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Information contained in this publication regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, MERCHANTABILITY OR FITNESS FOR PURPOSE. Microchip disclaims all liability arising from this information and its use. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights.

QUALITY MANAGEMENT SYSTEM CERTIFIED BY DNV = ISO/TS 16949=

Trademarks

The Microchip name and logo, the Microchip logo, dsPIC, FlashFlex, KEELOQ, KEELOQ logo, MPLAB, PIC, PICmicro, PICSTART, PIC³² logo, rfPIC, SST, SST Logo, SuperFlash and UNI/O are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

FilterLab, Hampshire, HI-TECH C, Linear Active Thermistor, MTP, SEEVAL and The Embedded Control Solutions Company are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Silicon Storage Technology is a registered trademark of Microchip Technology Inc. in other countries.

Analog-for-the-Digital Age, Application Maestro, BodyCom, chipKIT, chipKIT logo, CodeGuard, dsPICDEM, dsPICDEM.net, dsPICworks, dsSPEAK, ECAN, ECONOMONITOR, FanSense, HI-TIDE, In-Circuit Serial Programming, ICSP, Mindi, MiWi, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, mTouch, Omniscient Code Generation, PICC, PICC-18, PICDEM, PICDEM.net, PICkit, PICtail, REAL ICE, rfLAB, Select Mode, SQI, Serial Quad I/O, Total Endurance, TSHARC, UniWinDriver, WiperLock, ZENA and Z-Scale are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

GestIC and ULPP are registered trademarks of Microchip Technology Germany II GmbH & Co. & KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2012, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.

Printed on recycled paper.

ISBN: 978-1-62076-665-1

Microchip received ISO/TS-16949:2009 certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona; Gresham, Oregon and design centers in California and India. The Company's quality system processes and procedures are for its PIC® MCUs and dsPIC® DSCs, KEELOQ® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.



Worldwide Sales and Service

AMERICAS

Corporate Office 2355 West Chandler Blvd.

Chandler, AZ 85224-6199 Tel: 480-792-7200 Fax: 480-792-7277

Technical Support: http://www.microchip.com/

support

Web Address: www.microchip.com

Atlanta

Duluth, GA Tel: 678-957-9614 Fax: 678-957-1455

Boston

Westborough, MA Tel: 774-760-0087 Fax: 774-760-0088

Chicago Itasca, IL

Tel: 630-285-0071 Fax: 630-285-0075

Cleveland

Independence, OH Tel: 216-447-0464 Fax: 216-447-0643

Dallas

Addison, TX Tel: 972-818-7423 Fax: 972-818-2924

Detroit

Farmington Hills, MI Tel: 248-538-2250 Fax: 248-538-2260

Indianapolis Noblesville, IN

Tel: 317-773-8323 Fax: 317-773-5453

Los Angeles

Mission Viejo, CA Tel: 949-462-9523 Fax: 949-462-9608

Santa Clara

Santa Clara, CA Tel: 408-961-6444 Fax: 408-961-6445

Toronto

Mississauga, Ontario,

Canada

Tel: 905-673-0699 Fax: 905-673-6509

ASIA/PACIFIC

Asia Pacific Office

Suites 3707-14, 37th Floor Tower 6, The Gateway Harbour City, Kowloon Hong Kong

Tel: 852-2401-1200 Fax: 852-2401-3431

Australia - Sydney

Tel: 61-2-9868-6733 Fax: 61-2-9868-6755

China - Beijing

Tel: 86-10-8569-7000 Fax: 86-10-8528-2104

China - Chengdu

Tel: 86-28-8665-5511 Fax: 86-28-8665-7889

China - Chongqing

Tel: 86-23-8980-9588 Fax: 86-23-8980-9500

China - Hangzhou

Tel: 86-571-2819-3187 Fax: 86-571-2819-3189

China - Hong Kong SAR

Tel: 852-2401-1200 Fax: 852-2401-3431

China - Nanjing

Tel: 86-25-8473-2460 Fax: 86-25-8473-2470

China - Qingdao

Tel: 86-532-8502-7355 Fax: 86-532-8502-7205

China - Shanghai

Tel: 86-21-5407-5533 Fax: 86-21-5407-5066

China - Shenyang

Tel: 86-24-2334-2829 Fax: 86-24-2334-2393

China - Shenzhen

Tel: 86-755-8203-2660 Fax: 86-755-8203-1760

China - Wuhan

Tel: 86-27-5980-5300 Fax: 86-27-5980-5118

China - Xian

Tel: 86-29-8833-7252 Fax: 86-29-8833-7256

China - Xiamen

Tel: 86-592-2388138 Fax: 86-592-2388130

China - Zhuhai

Tel: 86-756-3210040 Fax: 86-756-3210049

ASIA/PACIFIC

India - Bangalore

Tel: 91-80-3090-4444 Fax: 91-80-3090-4123

India - New Delhi

Tel: 91-11-4160-8631 Fax: 91-11-4160-8632

India - Pune

Tel: 91-20-2566-1512 Fax: 91-20-2566-1513

Japan - Osaka

Tel: 81-66-152-7160 Fax: 81-66-152-9310

Japan - Yokohama

Tel: 81-45-471- 6166 Fax: 81-45-471-6122

Korea - Daegu

Tel: 82-53-744-4301 Fax: 82-53-744-4302

Korea - Seoul

Tel: 82-2-554-7200 Fax: 82-2-558-5932 or 82-2-558-5934

Malaysia - Kuala Lumpur

Tel: 60-3-6201-9857 Fax: 60-3-6201-9859

Malaysia - Penang

Tel: 60-4-227-8870 Fax: 60-4-227-4068

Philippines - Manila

Tel: 63-2-634-9065 Fax: 63-2-634-9069

Singapore

Tel: 65-6334-8870 Fax: 65-6334-8850

Taiwan - Hsin Chu

Tel: 886-3-5778-366 Fax: 886-3-5770-955

Taiwan - Kaohsiung

Tel: 886-7-213-7828 Fax: 886-7-330-9305

Taiwan - Taipei

Tel: 886-2-2508-8600 Fax: 886-2-2508-0102

Thailand - Bangkok

Tel: 66-2-694-1351 Fax: 66-2-694-1350

EUROPE

Austria - Wels

Tel: 43-7242-2244-39 Fax: 43-7242-2244-393

Denmark - Copenhagen

Tel: 45-4450-2828 Fax: 45-4485-2829

France - Paris

Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79

Germany - Munich

Tel: 49-89-627-144-0 Fax: 49-89-627-144-44

Italy - Milan

Tel: 39-0331-742611 Fax: 39-0331-466781

Netherlands - Drunen

Tel: 31-416-690399 Fax: 31-416-690340

Spain - Madrid

Tel: 34-91-708-08-90 Fax: 34-91-708-08-91

UK - Wokingham Tel: 44-118-921-5869 Fax: 44-118-921-5820

10/26/12

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Microchip:

MCP87050T-U/MF